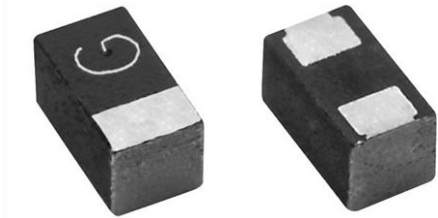


Solid Tantalum Chip Capacitors, MICROTAN[®], High CV Leadframeless Molded Automotive Grade



FEATURES

- Highest capacitance-voltage product in industry in given case size
- Small sizes include 0603 footprint
- Lead (Pb)-free L-shaped terminations
- AEC-Q200 qualified. PPAP available upon request
- 8 mm tape and reel packaging available per EIA-481
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

 AUTOMOTIVE
GRADE

RoHS
COMPLIANT
HALOGEN
FREE
GREEN
(5-2008)

PERFORMANCE/ELECTRICAL CHARACTERISTICS

www.vishay.com/doc?40215

Operating Temperature: -55 °C to +125 °C
(above 85 °C, voltage derating is required)

Capacitance Range: 1.0 μF to 100 μF

Capacitance Tolerance: ± 10 %, ± 20 %

Voltage Rating: 6.3 V_{DC} to 40 V_{DC}

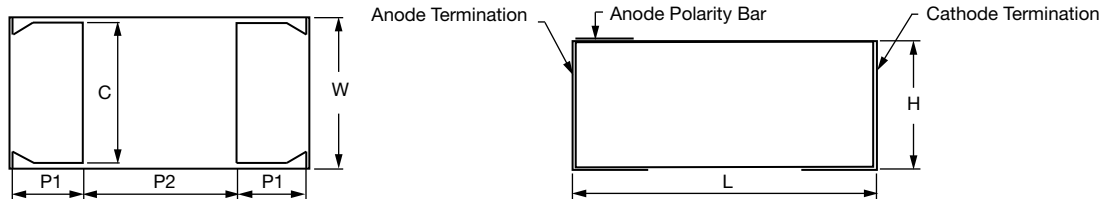
ORDERING INFORMATION

TP8 TYPE	M CASE CODE	105 CAPACITANCE	M CAPACITANCE TOLERANCE	010 DC VOLTAGE RATING AT +85 °C	C TERMINATION/ PACKAGING
	See Ratings and Case Codes table.	This is expressed in picofarads. The first two digits are the significant figures. The third is the number of zeros to follow.	K = ± 10 % M = ± 20 %	This is expressed in V. To complete the three-digit block, zeros precede the voltage rating. A decimal point is indicated by an "R" (6R3 = 6.3 V).	C = 100 % tin 7" [178 mm] reel

Note

- We reserve the right to supply higher voltage ratings and tighter capacitance tolerance capacitors in the same case size. Voltage substitutions will be marked with the higher voltage rating.

DIMENSIONS in inches [millimeters]



CASE CODE	L	W	H (MAX.)	P1	P2 (REF.)	C
M	0.063 ± 0.008 [1.60 ± 0.2]	0.033 ± 0.008 [0.85 ± 0.2]	0.035 [0.9]	0.020 ± 0.004 [0.50 ± 0.1]	0.024 [0.60]	0.024 ± 0.004 [0.60 ± 0.1]
W	0.079 ± 0.008 [2.00 ± 0.2]	0.050 ± 0.008 [1.25 ± 0.2]	0.048 [1.2]	0.020 ± 0.004 [0.50 ± 0.1]	0.040 [1.00]	0.035 ± 0.004 [0.90 ± 0.1]
R	0.081 ± 0.008 [2.05 ± 0.2]	0.053 ± 0.008 [1.35 ± 0.2]	0.063 [1.6]	0.020 ± 0.004 [0.50 ± 0.1]	0.043 [1.1]	0.035 ± 0.004 [0.9 ± 0.1]
P	0.094 ± 0.004 [2.4 ± 0.1]	0.057 ± 0.004 [1.45 ± 0.1]	0.047 [1.2]	0.020 ± 0.004 [0.50 ± 0.1]	0.057 [1.40]	0.035 ± 0.004 [0.90 ± 0.1]
A	0.126 ± 0.008 [3.2 ± 0.2]	0.063 ± 0.008 [1.6 ± 0.2]	0.071 [1.8]	0.031 ± 0.004 [0.80 ± 0.1]	0.063 [1.60]	0.047 ± 0.004 [1.20 ± 0.1]
N	0.138 ± 0.008 [3.5 ± 0.2]	0.112 ± 0.008 [2.8 ± 0.2]	0.048 [1.2]	0.031 ± 0.008 [0.80 ± 0.2]	0.077 [1.95]	0.094 ± 0.004 [2.4 ± 0.1]
T	0.138 ± 0.008 [3.5 ± 0.2]	0.112 ± 0.008 [2.8 ± 0.2]	0.063 [1.6]	0.031 ± 0.008 [0.80 ± 0.2]	0.077 [1.95]	0.094 ± 0.004 [2.4 ± 0.1]
B	0.138 ± 0.008 [3.5 ± 0.2]	0.112 ± 0.008 [2.8 ± 0.2]	0.08 [2.0]	0.031 ± 0.008 [0.80 ± 0.2]	0.077 [1.95]	0.094 ± 0.004 [2.4 ± 0.1]

RATINGS AND CASE CODES						
μF	6.3 V	10 V	16 V	20 V	25 V	40 V
1.0		M	M	M / W	R	P
2.2			M			
3.3		M		R		
4.7	M	M		P	P	
6.8		W		N / B		
10	M	R	A / R	A		
15		R				
22		A				
47		T / B				
100	A					

MARKING					
<p>M-Case</p> <p>Polarity bar Voltage code</p> <p>N, T, B-Case</p> <p>Polarity bar Capacitance Voltage</p> <p>Vishay marking</p>	VOLTAGE CODE		CAPACITANCE CODE		<p>P, R, W-Case</p> <p>Polarity bar Voltage code Capacitance code</p> <p>A-Case</p> <p>Polarity bar Voltage code EIA capacitance code (pF)</p>
	V	CODE	CAP, μF	CODE	
	6.3	J	1.0	A	
	10	A	2.2	J	
	16	C	3.3	N	
	20	D	4.7	S	
	25	E	6.8	W	
	35	V	10	α	
	40	g	15	e	
	50	T	22	j	
		33	n		
		47	s		
		68	w		
		100	\bar{A}		



STANDARD RATINGS						
CAPACITANCE (μ F)	CASE CODE	PART NUMBER	MAX. DCL AT +25 °C (μ A)	MAX. DF AT +25 °C 120 Hz (%)	MAX. ESR AT +25 °C 100 kHz (Ω)	MAX. RIPPLE 100 kHz I_{RMS} (A)
6.3 V_{DC} AT +85 °C; 4 V_{DC} AT +125 °C						
4.7	M	TP8M475M6R3C	0.50	8	6	0.06
10	M	TP8M106M6R3C	0.63	8	5	0.07
100	A	TP8A107(1)6R3C	6.30	30	3	0.16
10 V_{DC} AT +85 °C; 7 V_{DC} AT +125 °C						
1.0	M	TP8M105M010C	0.50	6	12	0.05
3.3	M	TP8M335(1)010C	0.50	8	6	0.06
4.7	M	TP8M475M010C	0.50	8	6	0.06
6.8	W	TP8W685(1)010C	0.68	8	8	0.06
10	R	TP8R106(1)010C	1.00	8	8	0.08
15	R	TP8R156(1)010C	1.50	8	5	0.09
22	A	TP8A226(1)010C	2.20	8	8	0.10
47	B	TP8B476(1)010C	4.70	8	2	0.20
47	T	TP8T476(1)010C	4.70	8	1	0.29
16 V_{DC} AT +85 °C; 10 V_{DC} AT +125 °C						
1.0	M	TP8M105M016C	0.50	6	12	0.05
2.2	M	TP8M225M016C	0.50	10	12	0.05
10	A	TP8A106(1)016C	1.60	8	6	0.11
10	R	TP8R106(1)016C	1.60	8	8	0.08
20 V_{DC} AT +85 °C; 13 V_{DC} AT +125 °C						
1.0	M	TP8M105M020C	0.50	6	12	0.05
1.0	W	TP8W105M020C	0.50	8	8	0.06
3.3	R	TP8R335(1)020C	0.70	8	8	0.08
4.7	P	TP8P475(1)020C	0.90	6	6	0.09
6.8	B	TP8B685(1)020C	1.36	8	6	0.12
6.8	N	TP8N685(1)020C	1.36	8	6	0.11
10	A	TP8A106(1)020C	2.00	8	3	0.16
25 V_{DC} AT +85 °C; 17 V_{DC} AT +125 °C						
1.0	R	TP8R105(1)025C	0.50	6	10	0.07
4.7	P	TP8P475(1)025C	1.20	6	6	0.09
40 V_{DC} AT +85 °C; 28 V_{DC} AT +125 °C						
1.0	P	TP8P105(1)040C	0.50	8	10	0.07

Note

- Part number definition:
(1) Tolerance: For 10 % tolerance, specify "K"; for 20 % tolerance, change to "M"



AEC-Q200 QUALIFICATION TESTING		
NO.	AEC-Q200 TEST ITEM	REFERENCE
1	Pre- and post stress electrical test	Internal spec
3	High temperature exposure (storage)	AEC-Q200
4	Temperature cycling	AEC-Q200
7	Biased humidity	AEC-Q200
8	Operational life	AEC-Q200
9	External visual	AEC-Q200
10	Physical dimension	AEC-Q200
12	Resistance to solvents	AEC-Q200
13	Mechanical shock	AEC-Q200
14	Vibration	AEC-Q200
15	Resistance to soldering heat	AEC-Q200
17	ESD	AEC-Q200
18	Solderability ⁽¹⁾	AEC-Q200
19	Electrical characterization	Internal spec
22	Terminal strength (SMD)	AEC-Q200

Note

⁽¹⁾ Exception: Instead of Solder Bath/Dip and Look Test (J-STD-002, method B at 215 °C, category 3) was performed "Method 2 - Surface Mount Process Simulation Test" per JESD22-B102E as specified in AEC-Q005 REV-A.

STANDARD PACKAGING QUANTITY	
CASE CODE	QUANTITY (pcs/reel)
	7" REEL
M	4000
W	2500
R	2500
P	3000
A	2000
N	2500
T	2500
B	2000

POWER DISSIPATION	
CASE CODE	MAXIMUM PERMISSIBLE POWER DISSIPATION AT +25 °C (W) IN FREE AIR
M	0.025
W	0.040
R	0.045
P	0.045
A	0.075
N	0.075
T	0.084
B	0.085

PRODUCT INFORMATION	
Micro Guide	www.vishay.com/doc?40115
Moisture Sensitivity	www.vishay.com/doc?40135
SELECTOR GUIDES	
Solid Tantalum Selector Guide	www.vishay.com/doc?49053
FAQ	
Frequently Asked Questions	www.vishay.com/doc?40110



Guide for Leadframeless Molded Tantalum Capacitors

INTRODUCTION

Tantalum electrolytic capacitors are the preferred choice in applications where volumetric efficiency, stable electrical parameters, high reliability, and long service life are primary considerations. The stability and resistance to elevated temperatures of the tantalum / tantalum oxide / manganese dioxide system make solid tantalum capacitors an appropriate choice for today's surface mount assembly technology.

Vishay Sprague has been a pioneer and leader in this field, producing a large variety of tantalum capacitor types for consumer, industrial, automotive, military, and aerospace electronic applications.

Tantalum is not found in its pure state. Rather, it is commonly found in a number of oxide minerals, often in combination with Columbium ore. This combination is known as "tantalite" when its contents are more than one-half tantalum. Important sources of tantalite include Australia, Brazil, Canada, China, and several African countries. Synthetic tantalite concentrates produced from tin slags in Thailand, Malaysia, and Brazil are also a significant raw material for tantalum production.

Electronic applications, and particularly capacitors, consume the largest share of world tantalum production. Other important applications for tantalum include cutting tools (tantalum carbide), high temperature super alloys, chemical processing equipment, medical implants, and military ordnance.

Vishay Sprague is a major user of tantalum materials in the form of powder and wire for capacitor elements and rod and sheet for high temperature vacuum processing.

THE BASICS OF TANTALUM CAPACITORS

Most metals form crystalline oxides which are non-protecting, such as rust on iron or black oxide on copper. A few metals form dense, stable, tightly adhering, electrically insulating oxides. These are the so-called "valve" metals and include titanium, zirconium, niobium, tantalum, hafnium, and aluminum. Only a few of these permit the accurate control of oxide thickness by electrochemical means. Of these, the most valuable for the electronics industry are aluminum and tantalum.

Capacitors are basic to all kinds of electrical equipment, from radios and television sets to missile controls and automobile ignitions. Their function is to store an electrical charge for later use.

Capacitors consist of two conducting surfaces, usually metal plates, whose function is to conduct electricity. They are separated by an insulating material or dielectric. The dielectric used in all tantalum electrolytic capacitors is tantalum pentoxide.

Tantalum pentoxide compound possesses high-dielectric strength and a high-dielectric constant. As capacitors are being manufactured, a film of tantalum pentoxide is applied to their electrodes by means of an electrolytic process. The film is applied in various thicknesses and at various voltages and although transparent to begin with, it takes on different colors as light refracts through it. This coloring occurs on the tantalum electrodes of all types of tantalum capacitors.

Rating for rating, tantalum capacitors tend to have as much as three times better capacitance / volume efficiency than aluminum electrolytic capacitors. An approximation of the capacitance / volume efficiency of other types of capacitors may be inferred from the following table, which shows the dielectric constant ranges of the various materials used in each type. Note that tantalum pentoxide has a dielectric constant of 26, some three times greater than that of aluminum oxide. This, in addition to the fact that extremely thin films can be deposited during the electrolytic process mentioned earlier, makes the tantalum capacitor extremely efficient with respect to the number of microfarads available per unit volume. The capacitance of any capacitor is determined by the surface area of the two conducting plates, the distance between the plates, and the dielectric constant of the insulating material between the plates.

COMPARISON OF CAPACITOR DIELECTRIC CONSTANTS

DIELECTRIC	ϵ DIELECTRIC CONSTANT
Air or Vacuum	1.0
Paper	2.0 to 6.0
Plastic	2.1 to 6.0
Mineral Oil	2.2 to 2.3
Silicone Oil	2.7 to 2.8
Quartz	3.8 to 4.4
Glass	4.8 to 8.0
Porcelain	5.1 to 5.9
Mica	5.4 to 8.7
Aluminum Oxide	8.4
Tantalum Pentoxide	26
Ceramic	12 to 400K

In the tantalum electrolytic capacitor, the distance between the plates is very small since it is only the thickness of the tantalum pentoxide film. As the dielectric constant of the tantalum pentoxide is high, the capacitance of a tantalum capacitor is high if the area of the plates is large:

$$C = \frac{\epsilon A}{t}$$

where

C = capacitance

ϵ = dielectric constant

A = surface area of the dielectric

t = thickness of the dielectric

Tantalum capacitors contain either liquid or solid electrolytes. In solid electrolyte capacitors, a dry material (manganese dioxide) forms the cathode plate. A tantalum lead is embedded in or welded to the pellet, which is in turn connected to a termination or lead wire. The drawings show the construction details of the surface mount types of tantalum capacitors shown in this catalog.

SOLID ELECTROLYTE TANTALUM CAPACITORS

Solid electrolyte capacitors contain manganese dioxide, which is formed on the tantalum pentoxide dielectric layer by impregnating the pellet with a solution of manganous nitrate. The pellet is then heated in an oven, and the manganous nitrate is converted to manganese dioxide.

The pellet is next coated with graphite, followed by a layer of metallic silver, which provides a conductive surface between the pellet and the leadframe.

Molded chip tantalum capacitor encases the element in plastic resins, such as epoxy materials. The molding compound has been selected to meet the requirements of UL 94 V-0 and outgassing requirements of ASTM E-595. After assembly, the capacitors are tested and inspected to assure long life and reliability. It offers excellent reliability and high stability for consumer and commercial electronics with the added feature of low cost.

Surface mount designs of “Solid Tantalum” capacitors use lead frames or lead frameless designs as shown in the accompanying drawings.

TANTALUM CAPACITORS FOR ALL DESIGN CONSIDERATIONS

Solid electrolyte designs are the least expensive for a given rating and are used in many applications where their very small size for a given unit of capacitance is of importance. They will typically withstand up to about 10 % of the rated DC working voltage in a reverse direction. Also important are their good low temperature performance characteristics and freedom from corrosive electrolytes.

Vishay Sprague patented the original solid electrolyte capacitors and was the first to market them in 1956. Vishay Sprague has the broadest line of tantalum capacitors and has continued its position of leadership in this field. Data sheets covering the various types and styles of Vishay Sprague capacitors for consumer and entertainment electronics, industry, and military applications are available where detailed performance characteristics must be specified.

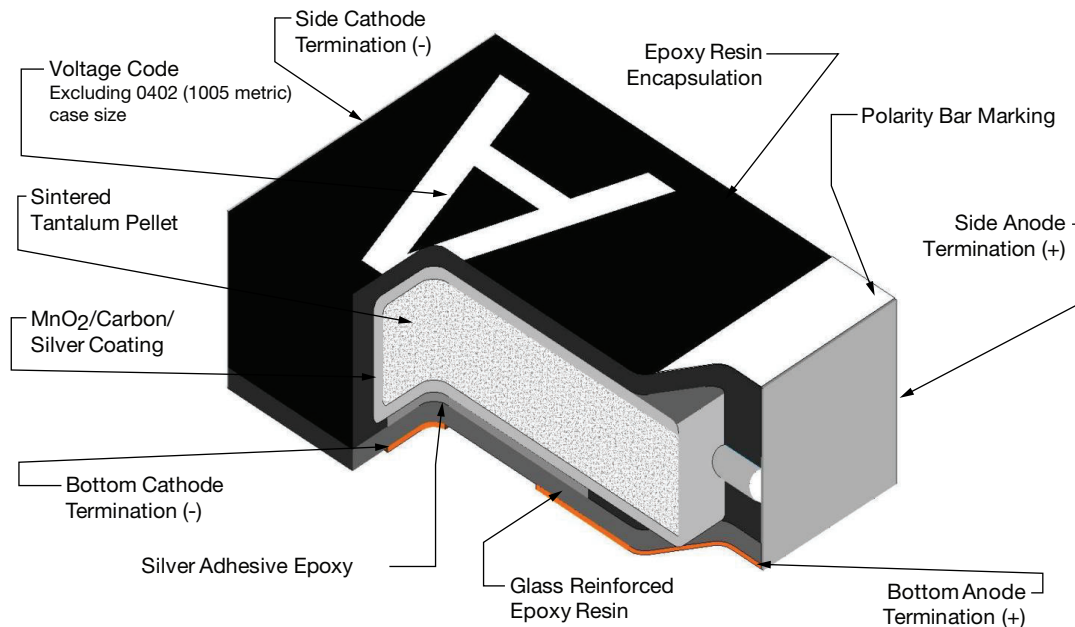
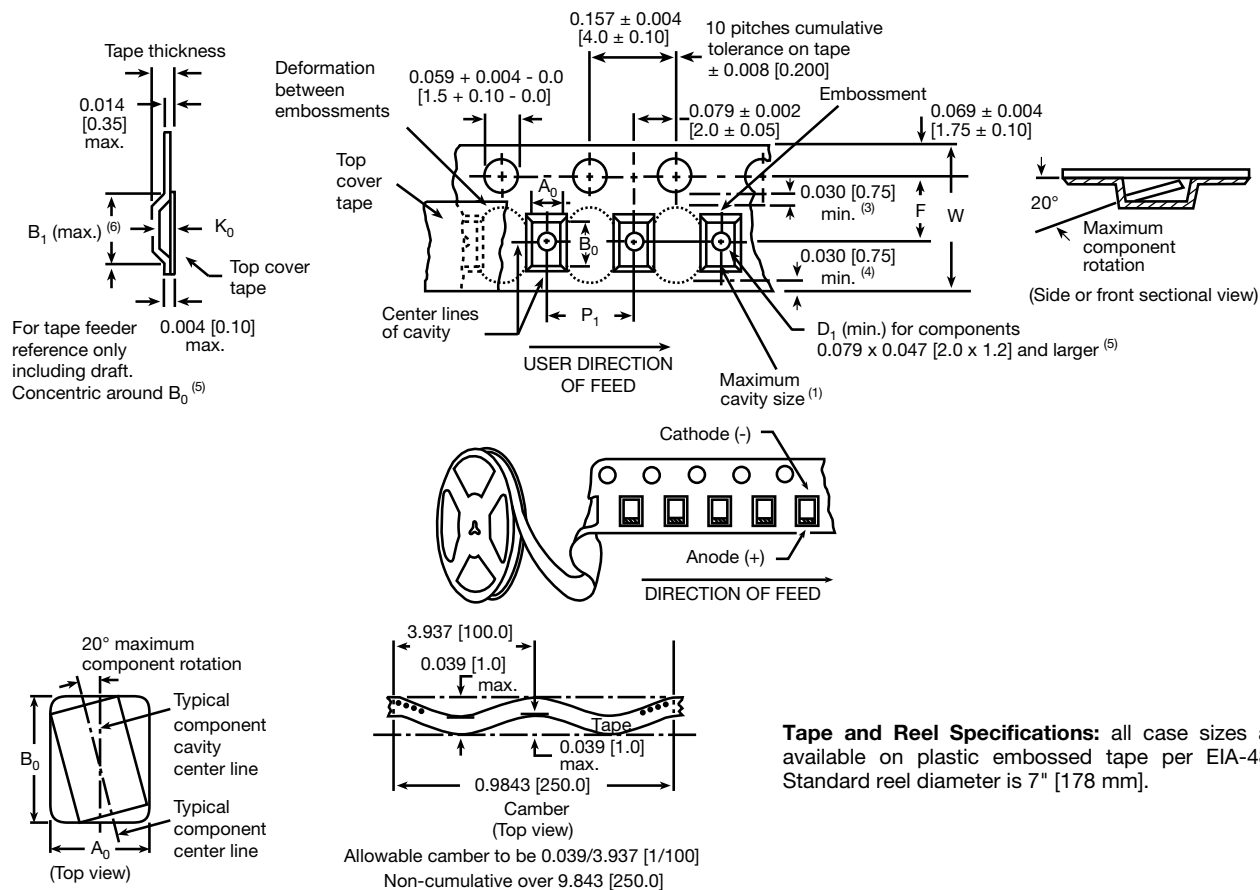


Fig. 1 - Leadframeless Molded Capacitors, All Types

SOLID TANTALUM CAPACITORS - LEADFRAMELESS MOLDED				
SERIES	TL8	298D	298W	TR8
PRODUCT IMAGE				
TYPE	Solid tantalum leadframeless molded chip capacitors			
FEATURES	Small size including 0603 and 0402 foot print			
	Ultra low profile	Industrial grade	Industrial grade, extended range	Low ESR
TEMPERATURE RANGE	Operating Temperature: -55 °C to +125 °C (above 40 °C, voltage derating is required)	Operating Temperature: -55 °C to +125 °C (above 85 °C, voltage derating is required)	Operating Temperature: -55 °C to +125 °C (above 40 °C, voltage derating is required)	Operating Temperature: -55 °C to +125 °C (above 85 °C, voltage derating is required)
CAPACITANCE RANGE	0.68 µF to 220 µF	0.33 µF to 220 µF	2.2 µF to 220 µF	1 µF to 220 µF
VOLTAGE RANGE	4 V to 25 V	2.5 V to 50 V	4 V to 16 V	2.5 V to 25 V
CAPACITANCE TOLERANCE	± 20 %, ± 10 %			
DISSIPATION FACTOR	6 % to 80 %	6 % to 80 %	30 % to 80 %	6 % to 80 %
CASE CODES	W9, A0, B0	K, M, R, P, Q, A, S, B	K, M, Q	M, R, P, Q, A, B
TERMINATION	100 % tin	100 % tin or gold plated		

SOLID TANTALUM CAPACITORS - LEADFRAMELESS MOLDED				
SERIES	TP8	TM8	DLA 11020	T42
PRODUCT IMAGE				
TYPE	Solid tantalum leadframeless molded chip capacitors			
FEATURES	Small size including 0603 and 0402 foot print			Built in fuse, double-stacked
	High performance, automotive grade	High reliability	High reliability, DLA approved	High reliability, ultra-low ESR
TEMPERATURE RANGE	Operating Temperature: -55 °C to +125 °C (above 85 °C, voltage derating is required)			
CAPACITANCE RANGE	1 µF to 100 µF	0.68 µF to 47 µF	1 µF to 47 µF	10 µF to 470 µF
VOLTAGE RANGE	6.3 V to 40 V	2 V to 40 V	6.3 V to 40 V	16 V to 75 V
CAPACITANCE TOLERANCE	± 20 %, ± 10 %			
DISSIPATION FACTOR	6 % to 30 %	6 % to 20 %	6 % to 8 %	6 % to 15 %
CASE CODES	M, W, R, P, A, N, T, B	K, M, G, W, R, P, A, N, T	M, W, R, P, A, N, T	M2
TERMINATION	100 % tin	Tin / lead solder plated, 100 % tin and gold plated	Tin / lead solder plated or gold plated	Tin / lead solder plated or 100 % tin

PLASTIC TAPE AND REEL PACKAGING in inches [millimeters]



Notes

- Metric dimensions will govern. Dimensions in inches are rounded and for reference only
- (1) A_0 , B_0 , K_0 , are determined by the maximum dimensions to the ends of the terminals extending from the component body and / or the body dimensions of the component. The clearance between the ends of the terminals or body of the component to the sides and depth of the cavity (A_0 , B_0 , K_0) must be within 0.002" (0.05 mm) minimum and 0.020" (0.50 mm) maximum. The clearance allowed must also prevent rotation of the component within the cavity of not more than 20°
- (2) Tape with components shall pass around radius "R" without damage. The minimum trailer length may require additional length to provide "R" minimum for 12 mm embossed tape for reels with hub diameters approaching N minimum
- (3) This dimension is the flat area from the edge of the sprocket hole to either outward deformation of the carrier tape between the embossed cavities or to the edge of the cavity whichever is less
- (4) This dimension is the flat area from the edge of the carrier tape opposite the sprocket holes to either the outward deformation of the carrier tape between the embossed cavity or to the edge of the cavity whichever is less
- (5) The embossed hole location shall be measured from the sprocket hole controlling the location of the embossment. Dimensions of embossment location shall be applied independent of each other
- (6) B_1 dimension is a reference dimension tape feeder clearance only

CARRIER TAPE DIMENSIONS in inches [millimeters] FOR 298D, 298W, TR8, TP8, TL8

CASE CODE	TAPE SIZE	B_1 (MAX.) ⁽¹⁾	D_1 (MIN.)	F	K_0 (MAX.)	P_1	W
M ⁽²⁾	8 mm	0.075 [1.91]	0.02 [0.5]	0.138 [3.5]	0.043 [1.10]	0.157 [4.0]	0.315 [8.0]
W	8 mm	0.112 [2.85]	0.039 [1.0]	0.138 [3.5]	0.053 [1.35]	0.157 [4.0]	0.315 [8.0]
R	8 mm	0.098 [2.46]	0.039 [1.0]	0.138 [3.5]	0.066 [1.71]	0.157 [4.0]	0.315 [8.0]
P	8 mm	0.108 [2.75]	0.02 [0.5]	0.138 [3.5]	0.054 [1.37]	0.157 [4.0]	0.315 [8.0]
A	8 mm	0.153 [3.90]	0.039 [1.0]	0.138 [3.5]	0.078 [2.00]	0.157 [4.0]	0.315 [8.0]
A0, Q	8 mm	-	0.02 [0.5]	0.138 [3.5]	0.049 [1.25]	0.157 [4.0]	0.315 [8.0]
B	8 mm	0.157 [4.0]	0.039 [1.0]	0.138 [3.5]	0.087 [2.22]	0.157 [4.0]	0.315 [8.0]
W9, S	8 mm	0.126 [3.20]	0.029 [0.75]	0.138 [3.5]	0.045 [1.15]	0.157 [4.0]	0.315 [8.0]
B0	12 mm	0.181 [4.61]	0.059 [1.5]	0.217 [5.5]	0.049 [1.25]	0.157 [4.0]	0.472 [12.0]

Notes

- (1) For reference only
- (2) Packaging of M case in plastic tape is available per request

CARRIER TAPE DIMENSIONS in inches [millimeters] FOR TM8							
CASE CODE	TAPE SIZE	B ₁ (MAX.) ⁽¹⁾	D ₁ (MIN.)	F	K ₀ (MAX.)	P ₁	W
M	8 mm	0.075 [1.91]	0.02 [0.5]	0.138 [3.5]	0.043 [1.10]	0.157 [4.0]	0.315 [8.0]
G	8 mm	0.077 [1.96]	0.02 [0.5]	0.138 [3.5]	0.051 [1.30]	0.157 [4.0]	0.315 [8.0]
W	8 mm	0.112 [2.85]	0.039 [1.0]	0.138 [3.5]	0.053 [1.35]	0.157 [4.0]	0.315 [8.0]
R	8 mm	0.098 [2.46]	0.039 [1.0]	0.138 [3.5]	0.066 [1.71]	0.157 [4.0]	0.315 [8.0]
P	8 mm	0.108 [2.75]	0.02 [0.5]	0.138 [3.5]	0.054 [1.37]	0.157 [4.0]	0.315 [8.0]
A	8 mm	0.153 [3.90]	0.039 [1.0]	0.138 [3.5]	0.078 [2.00]	0.157 [4.0]	0.315 [8.0]
N	12 mm	0.154 [3.90]	0.059 [1.5]	0.216 [5.5]	0.051 [1.30]	0.157 [4.0]	0.472 [12.0]
T	12 mm	0.154 [3.90]	0.059 [1.5]	0.216 [5.5]	0.067 [1.70]	0.157 [4.0]	0.472 [12.0]

Notes

⁽¹⁾ For reference only

CARRIER TAPE DIMENSIONS in inches [millimeters] FOR T42							
CASE CODE	TAPE SIZE	B ₁ (MAX.) ⁽¹⁾	D ₁ (MIN.)	F	K ₀ (MAX.)	P ₁	W
M2	16 mm	0.404 [10.3]	0.059 [1.5]	0.295 [7.5]	0.176 [4.5]	0.472 [12.0]	0.630 [16.0]

Note

⁽¹⁾ For reference only

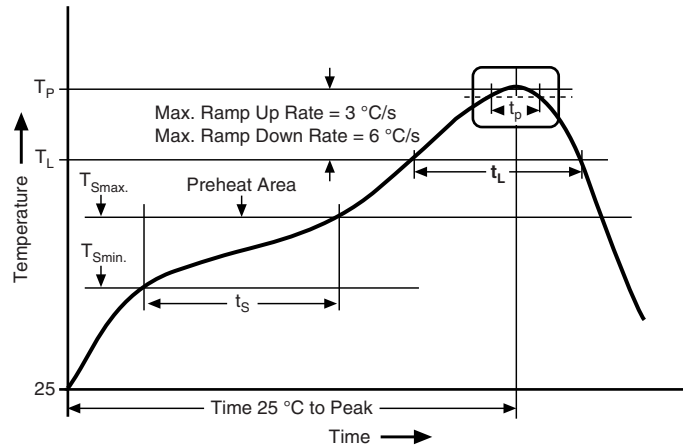
PAPER TAPE AND REEL PACKAGING in inches [millimeters] FOR 298D, 298W, TR8, TP8, TL8, TM8 (K case only)											
<p>[10 pitches cumulative tolerance on tape ± 0.2 mm]</p> <p>Bottom cover tape, Top cover tape, Cavity center lines, Anode, Cavity size ⁽¹⁾, Bottom cover tape, USER FEED DIRECTION</p>											
CASE SIZE	TAPE SIZE	A ₀	B ₀	D ₀	P ₀	P ₁	P ₂	E	F	W	T
K	8 mm	0.033 ± 0.002 [0.85 ± 0.05]	0.053 ± 0.002 [1.35 ± 0.05]	0.06 ± 0.004 [1.5 ± 0.1]	0.157 ± 0.004 [4.0 ± 0.1]	0.078 ± 0.004 [2.0 ± 0.1]	0.079 ± 0.002 [2.0 ± 0.05]	0.069 ± 0.004 [1.75 ± 0.1]	0.0138 ± 0.002 [3.5 ± 0.05]	0.315 ± 0.008 [8.0 ± 0.2]	0.03 ± 0.002 [0.75 ± 0.05]
M	8 mm	0.041 ± 0.002 [1.05 ± 0.05]	0.071 ± 0.002 [1.8 ± 0.05]	0.06 ± 0.004 [1.5 ± 0.1]	0.157 ± 0.004 [4.0 ± 0.1]	0.157 ± 0.004 [4.0 ± 0.1]	0.079 ± 0.002 [2.0 ± 0.05]	0.069 ± 0.004 [1.75 ± 0.1]	0.0138 ± 0.002 [3.5 ± 0.05]	0.315 ± 0.008 [8.0 ± 0.2]	0.037 ± 0.002 [0.95 ± 0.05]

Note

⁽¹⁾ A₀, B₀ are determined by the maximum dimensions to the ends of the terminals extending from the component body and / or the body dimensions of the component. The clearance between the ends of the terminals or body of the component to the sides and depth of the cavity (A₀, B₀) must be within 0.002" (0.05 mm) minimum and 0.020" (0.50 mm) maximum. The clearance allowed must also prevent rotation of the component within the cavity of not more than 20°

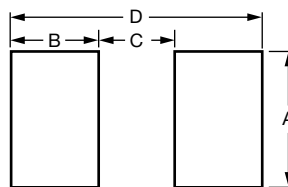
RECOMMENDED REFLOW PROFILES

Capacitors should withstand reflow profile as per J-STD-020 standard, three cycles.



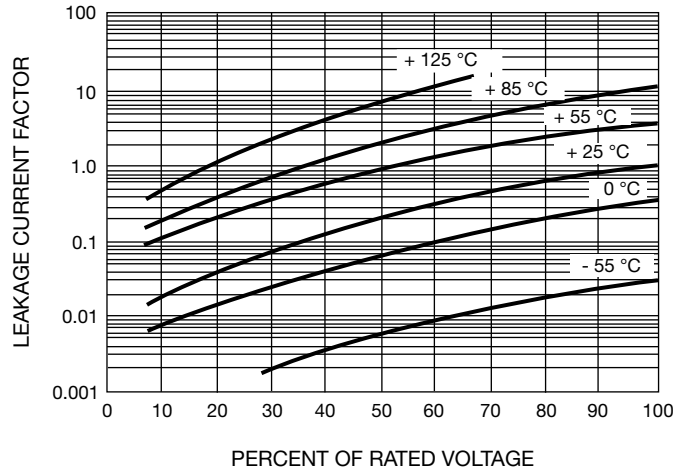
PROFILE FEATURE	SnPb EUTECTIC ASSEMBLY	LEAD (Pb)-FREE ASSEMBLY
PREHEAT AND SOAK		
Temperature min. ($T_{Smin.}$)	100 °C	150 °C
Temperature max. ($T_{Smax.}$)	150 °C	200 °C
Time (t_s) from ($T_{Smin.}$ to $T_{Smax.}$)	60 s to 90 s	60 s to 150 s
RAMP UP		
Ramp-up rate (T_L to T_P)	3 °C/s maximum	
Liquidus temperature (T_L)	183 °C	217 °C
Time (t_L) maintained above T_L	60 s to 150 s	
Peak package body temperature (T_P) max.	235 °C	260 °C
Time (t_p) within 5 °C of the peak max. temperature	20 s	30 s
RAMP DOWN		
Ramp-down rate (T_P to T_L)	6 °C/s maximum	
Time from 25 °C to peak temperature	6 min maximum	8 min maximum

PAD DIMENSIONS in inches [millimeters]



CASE CODE	A (NOM.)	B (MIN.)	C (NOM.)	D (MIN.)
K	0.021 [0.53]	0.016 [0.41]	0.022 [0.55]	0.054 [1.37]
M, G	0.024 [0.61]	0.027 [0.70]	0.025 [0.64]	0.080 [2.03]
R, W9, S	0.035 [0.89]	0.029 [0.74]	0.041 [1.05]	0.099 [2.52]
W	0.035 [0.89]	0.029 [0.74]	0.037 [0.95]	0.095 [2.41]
P	0.035 [0.89]	0.029 [0.74]	0.054 [1.37]	0.112 [2.84]
A, Q, A0	0.047 [1.19]	0.042 [1.06]	0.065 [1.65]	0.148 [3.76]
B, B0	0.094 [2.39]	0.044 [1.11]	0.072 [1.82]	0.159 [4.03]
N, T	0.094 [2.39]	0.044 [1.11]	0.065 [1.65]	0.152 [3.86]
M2	0.315 [8.00]	0.098 [2.50]	0.197 [5.00]	0.394 [10.0]

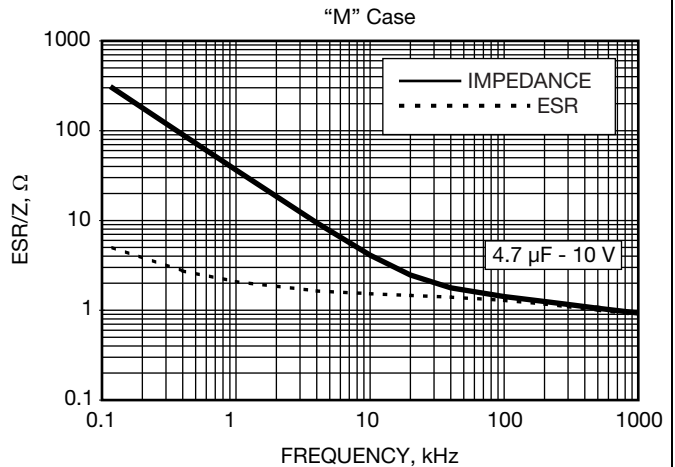
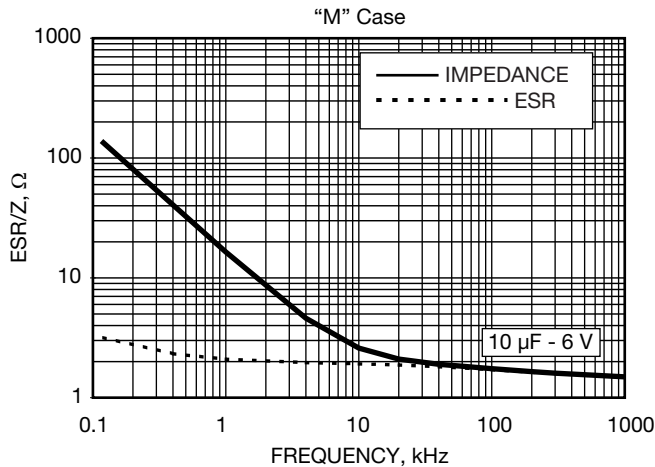
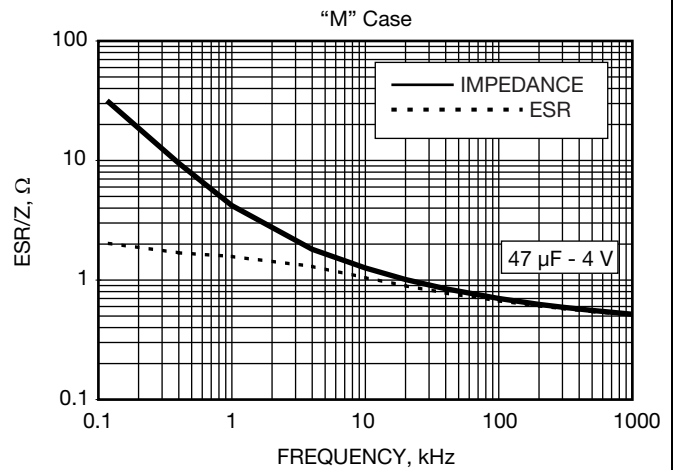
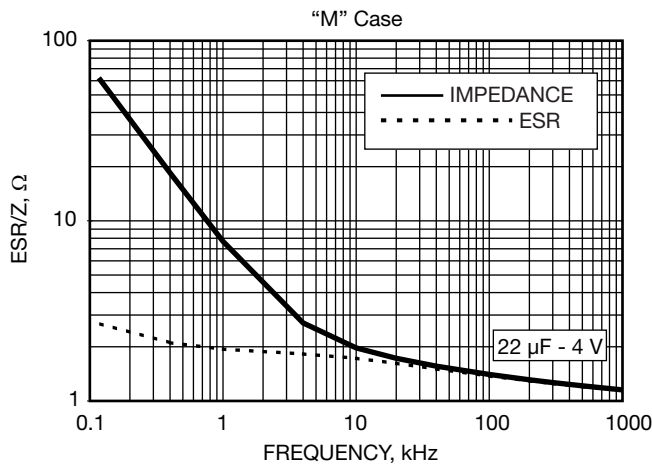
TYPICAL LEAKAGE CURRENT FACTOR RANGE



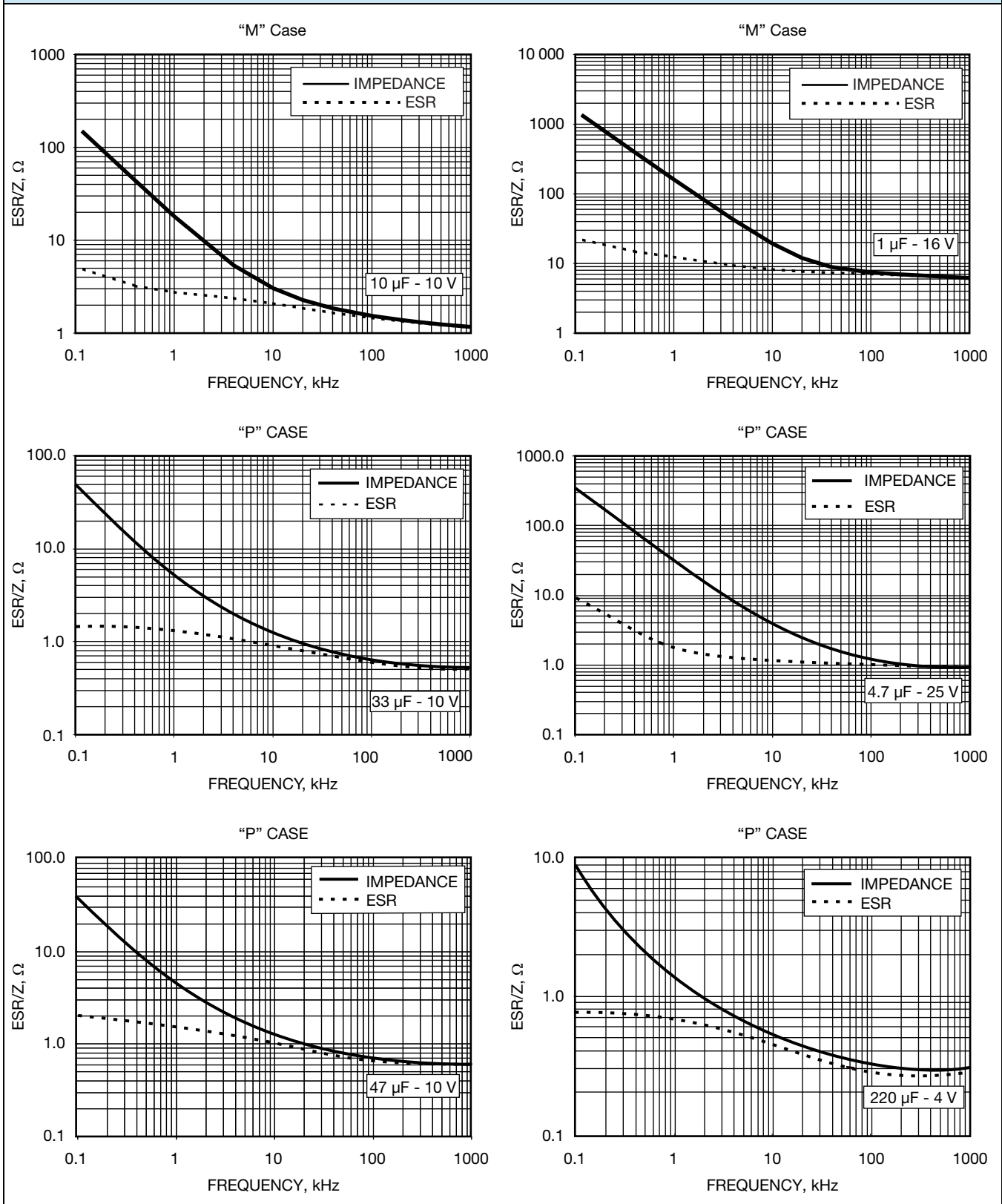
Notes

- At +25 °C, the leakage current shall not exceed the value listed in the Standard Ratings table
- At +85 °C, the leakage current shall not exceed 10 times the value listed in the Standard Ratings table
- At +125 °C, the leakage current shall not exceed 12 times the value listed in the Standard Ratings table

TYPICAL CURVES AT +25 °C, IMPEDANCE AND ESR VS. FREQUENCY



TYPICAL CURVES AT +25 °C, IMPEDANCE AND ESR VS. FREQUENCY



GUIDE TO APPLICATION

1. **AC Ripple Current:** the maximum allowable ripple current shall be determined from the formula:

$$I_{RMS} = \sqrt{\frac{P}{R_{ESR}}}$$

where,

P = power dissipation in watts at +25 °C (see paragraph number 5 and the table Power Dissipation as given in the tables in the product datasheets)

R_{ESR} = the capacitor equivalent series resistance at the specified frequency

2. **AC Ripple Voltage:** the maximum allowable ripple voltage shall be determined from the formula:

$$V_{RMS} = Z \sqrt{\frac{P}{R_{ESR}}}$$

or, from the formula:

$$V_{RMS} = I_{RMS} \times Z$$

where,

P = power dissipation in watts at +25 °C (see paragraph number 5 and the table Power Dissipation as given in the tables in the product datasheets)

R_{ESR} = the capacitor equivalent series resistance at the specified frequency

Z = the capacitor impedance at the specified frequency

- 2.1 The sum of the peak AC voltage plus the applied DC voltage shall not exceed the DC voltage rating of the capacitor.
- 2.2 The sum of the negative peak AC voltage plus the applied DC voltage shall not allow a voltage reversal exceeding 10 % of the DC working voltage at +25 °C.
3. **Reverse Voltage:** these capacitors are capable of withstanding peak voltages in the reverse direction equal to 10 % of the DC rating at +25 °C, 5 % of the DC rating at +85 °C, and 1 % of the DC rating at +125 °C.
4. **Temperature Derating:** if these capacitors are to be operated at temperatures above +25 °C, the permissible RMS ripple current shall be calculated using the derating factors as shown:

TEMPERATURE	DERATING FACTOR
+25 °C	1.0
+85 °C	0.9
+125 °C	0.4

5. **Power Dissipation:** power dissipation will be affected by the heat sinking capability of the mounting surface. Non-sinusoidal ripple current may produce heating effects which differ from those shown. It is important that the equivalent I_{RMS} value be established when calculating permissible operating levels. (Power Dissipation calculated using +25 °C temperature rise.)

6. **Printed Circuit Board Materials:** molded capacitors are compatible with commonly used printed circuit board materials (alumina substrates, FR4, FR5, G10, PTFE-fluorocarbon and porcelainized steel).

7. **Attachment:**

- 7.1 **Solder Paste:** the recommended thickness of the solder paste after application is 0.007" ± 0.001" [0.178 mm ± 0.025 mm]. Care should be exercised in selecting the solder paste. The metal purity should be as high as practical. The flux (in the paste) must be active enough to remove the oxides formed on the metallization prior to the exposure to soldering heat. In practice this can be aided by extending the solder preheat time at temperatures below the liquidous state of the solder.

- 7.2 **Soldering:** capacitors can be attached by conventional soldering techniques; vapor phase, convection reflow, infrared reflow, wave soldering and hot plate methods. The Soldering Profile charts show recommended time / temperature conditions for soldering. Preheating is recommended. The recommended maximum ramp rate is 2 °C per s. Attachment with a soldering iron is not recommended due to the difficulty of controlling temperature and time at temperature. The soldering iron must never come in contact with the capacitor. For details see www.vishay.com/doc?40214.

- 7.2.1 **Backward and Forward Compatibility:** capacitors with SnPb or 100 % tin termination finishes can be soldered using SnPb or lead (Pb)-free soldering processes.

8. **Cleaning (Flux Removal) After Soldering:** molded capacitors are compatible with all commonly used solvents such as TES, TMS, Prelete, Chloroethane, Terpene and aqueous cleaning media. However, CFC / ODS products are not used in the production of these devices and are not recommended. Solvents containing methylene chloride or other epoxy solvents should be avoided since these will attack the epoxy encapsulation material.

- 8.1 When using ultrasonic cleaning, the board may resonate if the output power is too high. This vibration can cause cracking or a decrease in the adherence of the termination. DO NOT EXCEED 9W/l at 40 kHz for 2 min.

9. **Recommended Mounting Pad Geometries:** proper mounting pad geometries are essential for successful solder connections. These dimensions are highly process sensitive and should be designed to minimize component rework due to unacceptable solder joints. The dimensional configurations shown are the recommended pad geometries for both wave and reflow soldering techniques. These dimensions are intended to be a starting point for circuit board designers and may be fine tuned if necessary based upon the peculiarities of the soldering process and / or circuit board design.



Molded Chip Tantalum Capacitors, Automotive Grade

ELECTRICAL PERFORMANCE CHARACTERISTICS					
ITEM	PERFORMANCE CHARACTERISTICS				
Category temperature range	-55 °C to +85 °C (to +125 °C / +150 °C / +175 °C with voltage derating - refer to graph "Category Voltage vs. Temperature") ⁽¹⁾				
Capacitance tolerance	± 20 %, ± 10 %, tested via bridge method, at 25 °C, 120 Hz				
Dissipation factor	Limits per Standard Ratings table. Tested via bridge method, at 25 °C, 120 Hz				
ESR	Limits per Standard Ratings table. Tested via bridge method, at 25 °C, 100 kHz				
Leakage current	After application of rated voltage applied to capacitors for 5 min using a steady source of power with 1 kΩ resistor in series with the capacitor under test, leakage current at 25 °C is not more than 0.01 CV or 0.5 μA, whichever is greater. <i>Note that the leakage current varies with temperature and applied voltage. See graph "Typical Leakage Current Temperature Factor" for the appropriate adjustment factor.</i>				
Capacitance change by temperature	+30 % max. (at +175 °C) +20 % max. (at +125 °C and +150 °C) +10 % max. (at +85 °C) -10 % max. (at -55 °C)				
Reverse voltage	Capacitors are capable of withstanding peak voltages in the reverse direction equal to: 10 % of the DC rating at +25 °C 5 % of the DC rating at +85 °C 1 % of the DC rating at +125 °C				
Ripple current	For maximum ripple current values (at 25 °C) refer to relevant datasheet. If capacitors are to be used at temperatures above +25 °C, the permissible RMS ripple current (or voltage) shall be calculated using the derating factors: 1.0 at +25 °C 0.9 at +85 °C 0.4 at +125 °C 0.3 at +150 °C 0.2 at +175 °C				
Maximum operating and surge voltages vs. temperature	+85 °C		+125 °C		+150 °C / +175 °C
	RATED VOLTAGE (V)	SURGE VOLTAGE (V)	CATEGORY VOLTAGE (V)	SURGE VOLTAGE (V)	CATEGORY VOLTAGE (V)
	4	5.2	2.7	3.4	n/a
	6.3	8	4	5	3
	10	13	7	8	5
	16	20	10	12	8
	20	26	13	16	10
	25	32	17	20	12.5
	35	46	23	28	17.5
	50	65	33	40	25
	50 ⁽²⁾	60	33	40	n/a
	63	75	42	50	n/a
75 ⁽³⁾	75	50	50	n/a	

Notes

- All information presented in this document reflects typical performance characteristics
- (1) Series TH3 - up to 150 °C; TH4 - up to 175 °C
- (2) Capacitance value 15 μF and higher
- (3) For 293D and TR3 only

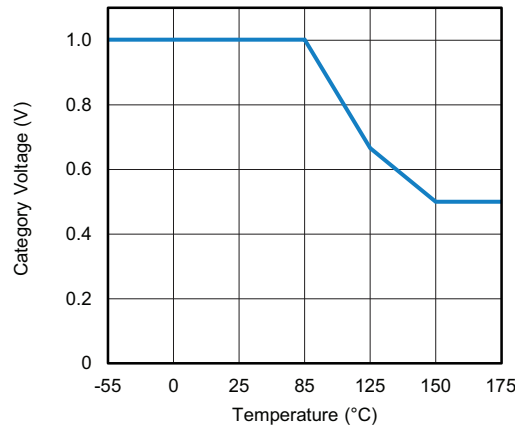


RECOMMENDED VOLTAGE DERATING GUIDELINES (for temperature below +85 °C)	
VOLTAGE RAIL	CAPACITOR VOLTAGE RATING
≤ 3.3	6.3
5	10
10	20
12	25
15	35
≥ 24	50 or series configuration

Notes

- For temperatures above +85 °C the same voltage derating ratio is recommended, but with respect to category voltage.
 Up to +85 °C: category voltage = rated voltage
 At +125 °C: category voltage = 2/3 of rated voltage
 At 150 °C / 175 °C: category voltage = 1/2 of rated voltage
- For more information about recommended voltage derating see: www.vishay.com/doc?40246

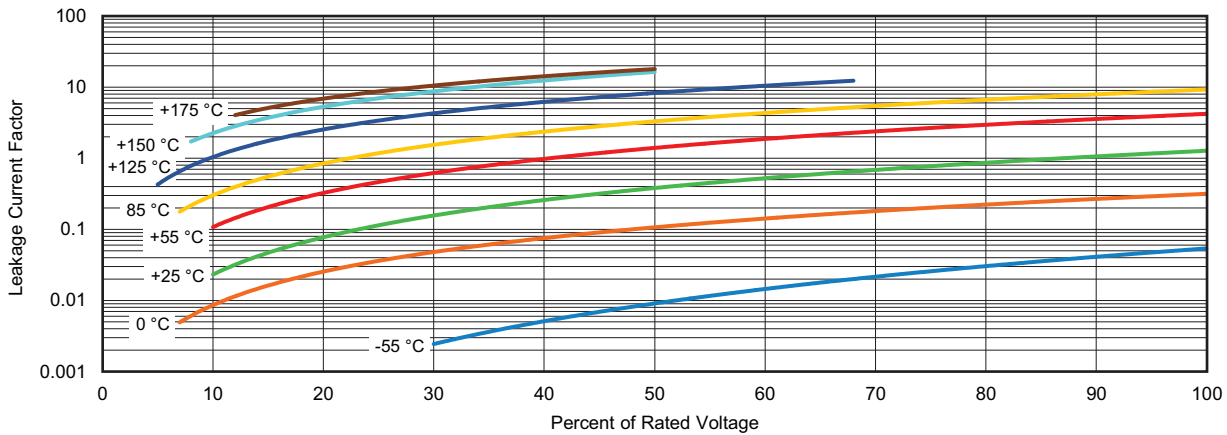
CATEGORY VOLTAGE VS. TEMPERATURE



Note

- Below 85 °C category voltage is equal to rated voltage

TYPICAL LEAKAGE CURRENT FACTOR



Note

- At +25 °C, the leakage current shall not exceed the value listed in the Standard Ratings table.
- At +85 °C, the leakage current shall not exceed 10 times the value listed in the Standard Ratings table.
- At +125 °C, the leakage current shall not exceed 12 times the value listed in the Standard Ratings table.
- At +150 °C, the leakage current shall not exceed 15 times the value listed in the Standard Ratings table.
- At +175 °C, the leakage current shall not exceed 18 times the value listed in the Standard Ratings table



ENVIRONMENTAL PERFORMANCE CHARACTERISTICS			
ITEM	CONDITION	POST TEST PERFORMANCE	
High temperature exposure (storage)	MIL-STD-202, method 108 1000 h, at maximum rated temperature, unpowered	Capacitance change Dissipation factor Leakage current ESR	Within ± 20 % of initial value Initial specified limit Initial specified limit Initial specified limit
Operational life test at +125 °C	AEC-Q200 1000 h application 2/3 of rated voltage	Capacitance change Dissipation factor Leakage current ESR	Within ± 20 % of initial value Initial specified limit Shall not exceed 10 times the initial limit Initial specified limit
Operational life test at +150 °C (for TH3) and at +175 °C (for TH4)	AEC-Q200 1000 h application 1/2 of rated voltage	Capacitance change Dissipation factor Leakage current ESR	Within ± 20 % of initial value Shall not exceed 3 times the initial limit Shall not exceed 10 times the initial limit Shall not exceed 3 times the initial limit
Surge voltage	MIL-PRF-55365: 1000 successive test cycles at 85 °C of surge voltage (as specified in the table above), in series with a 33 Ω resistor at the rate of 30 s ON, 30 s OFF	Capacitance change Dissipation factor Leakage current ESR	Within ± 30 % of initial value Shall not exceed 1.5 times the initial limit Shall not exceed 2 times the initial limit Shall not exceed 1.5 times the initial limit
Biased humidity test	AEC-Q200 At 85 °C / 85 % RH, 1000 h, with rated voltage applied	Capacitance change Dissipation factor Leakage current ESR	Within ± 20 % of initial value Shall not exceed 3 times the initial limit Shall not exceed 10 times the initial limit Shall not exceed 3 times the initial limit
Temperature cycling	AEC-Q200 / JESD22, method JA-104 -55 °C / +125 °C, for 1000 cycles	Capacitance change Dissipation factor Leakage current ESR	Within ± 20 % of initial value Initial specified limit Initial specified limit Initial specified limit

MECHANICAL PERFORMANCE CHARACTERISTICS			
ITEM	CONDITION	POST TEST PERFORMANCE	
Vibration	MIL-STD-202, method 204: 10 Hz to 2000 Hz, 5 g peak for 20 min, 12 cycles each of 3 orientations (total 36 cycles), at rated voltage	Capacitance change Dissipation factor Leakage current	Within ± 20 % of initial value Initial specified limit Initial specified limit
Mechanical shock	MIL-STD-202, method 213, condition F, 1500 g peak, 0.5 ms, half-sine	Capacitance change Dissipation factor Leakage current	Within ± 20 % of initial value Initial specified limit Initial specified limit
Resistance to solder heat	MIL-STD-202, method 210, condition D Solder dip 260 °C ± 5 °C, 10 s	Capacitance change Dissipation factor Leakage current	Within ± 20 % of initial value Initial specified limit Initial specified limit
Resistance to solvents	MIL-STD-202, method 215	Capacitance change Dissipation factor Leakage current	Within ± 20 % of initial value Initial specified limit Initial specified limit
Solderability	AEC-Q200 / J-STD-002	Electrical test not required	
Terminal strength / Shear force test	AEC-Q200-006 Apply a pressure load of 17.7 N (1.8 kg) for 60 s horizontally to the center of capacitor side body Exception: for case size 0603 pressure load is 5N	Part should not be sheared off the pads and no body cracking post-conditioning. Electrical test not required.	
Flammability	Encapsulation materials meet UL 94 V-0 with an oxygen index of 32 %	n/a	



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